SiC SBD P3D06020T2 650V SiC Schottky Diode

Features

- Qualified to AEC-Q101
- Ultra-Fast Switching
- Zero Reverse Recovery Current
- High-Frequency Operation
- Positive Temperature Coefficient on V_F
- High Surge Current
- 100% UIS tested



- Improve System Efficiency
- Reduction of Heat Sink Requirement
- Essentially No Switching Losses
- Parallel Devices Without Thermal Runaway

Applications

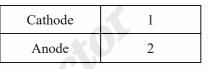
- Consumer SMPS
- Boost Diodes in PFC or DC/DC Stages
- AC/DC Converters

Order Information

Part Number	Package	Marking
P3D06020T2	TO-220-2	P3D06020T2



TO-220-2











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1. Maximum Ratings

At T_J= 25°C, unless specified otherwise

Parameter	Symbol	Value	Unit	Test condition
Repetitive Peak Reverse Voltage	V _{RRM}	650	V	T _C = 25°C
Surge Peak Reverse Voltage	V _{RSM}	650	V	T _C = 25°C
DC Blocking Voltage	V _R	650	V	T _C = 25°C
Forward Current	I _F	48 27 20	A	T _C = 25°C T _C = 125°C T _C = 145°C
Repetitive Peak Forward Surge Current	I _{FRM}	83 47	A	T_{c} = 25°C, t_{p} = 10ms T_{c} = 125°C, t_{p} = 10ms
Non-Repetitive Forward Surge Current	I _{FSM}	120 100	A	T_{c} = 25°C, t_{p} = 10ms T_{c} = 125°C, t_{p} = 10ms
Power Dissipation	P _{tot}	186	W	T _C = 25°C
Operating Junction and Storage Temperature	T _J , T _{STG}	-55 to +175	°C	
TO-220 Mounting Torque M3 Screw	T _{orq}	1 8.8	Nm Ibf-in	

2. Thermal Characteristics

Parameter	Symbol	Values	Unit
Thermal Resistance from Junction to Case	R _{θJC}	0.81	°C/W

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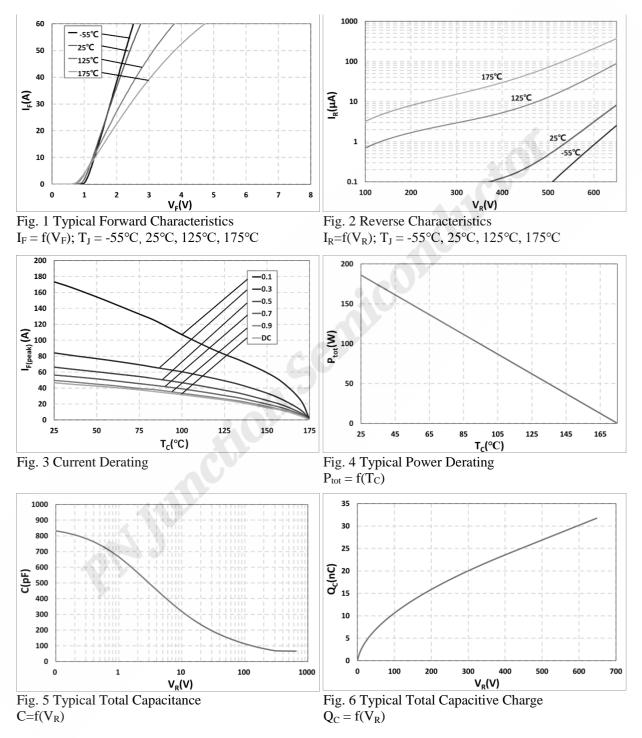
3. Electrical Characteristics

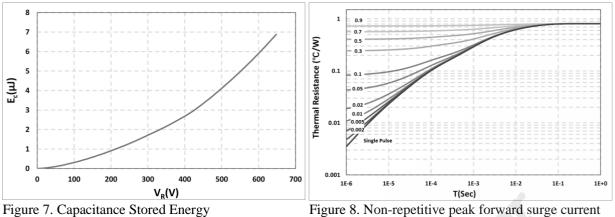
At T_J= 25°C, unless specified otherwise

Parameter	Gunahal	Values			11	To stand it is a	
Parameter	Symbol	Min.	Тур.	Max.	Unit	Test condition	
	V	/	1.51	1.7	V	I _F = 20A, T _J = 25°C	
Forward Voltage	V _F	/	1.76	/		I _F = 20A, T _J = 175℃	
Doverse Current		/	5.01	100	μΑ	V _R = 650V, T _J = 25°C	
Reverse Current	I _R	/	377	1		V _R = 650V, T _J = 175°C	
Total Capacitance	с		859.5		pF	V _R = 0V, T _J = 25°C f= 1MHz	
			82.8	1		V _R = 200V, T _J = 25°C f= 1MHz	
			67.8			V _R = 400V, T _J = 25°C f= 1MHz	
Total Capacitive Charge	Qc	/	23.6	/	nC	V _R = 400V, I _F = 20A T _J = 25°C	
Capacitance Stored Energy	E _C	/	2.7	/	μ	V _R = 400V	

4. Typical Performance

At T_J= 25°C, unless specified otherwise

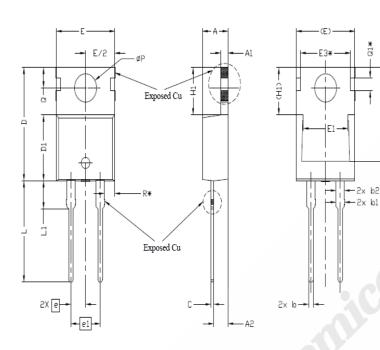




 $E_C = f(V_R)$

7. Capacitance Stored Energy 7_R)
Figure 8. Non-repetitive peak forward surge current versus pulse duration (sinusoidal waveform)

5. Package Outlines



SYMBOL	[NOTES		
STMBUL	MIN.	NOM.	MAX.	NOTES
Α	4.24	4.44	4.64	
A1	1.15	1.27	1.40	
A2	2.30	2.48	2.70	
b	0.70	0.80	0.90	
b1	1.20	1.55	1.75	
b2	1.20	1.45	1.45 1.70	
с	0.40	0.50	0.60	
D	14.70	15.37	16.00	4
D1	8.82	8.92	9.02	
D2	12.63	12.73	12,83	5
E	9.96	10.16	10.36	4,5
E1	6.86	7.77	8.89	5
E3*				
е				
e1				
H1	6.30	6.45	6.60	5,6
L	13.47	13.72	13.97	
L1	3.60	3.80	4,00	
ØP	3.75	3.84	3.93	
Q	2.60	2.80	3.00	
Q1*				
R*		1.82REF.		

Drawing and Dimensions

Q1¥

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